

NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DDC (XXXX) UQs are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Part Number	R1 (NOM)	R2 (NOM)
DDC124EU	22kΩ	22kΩ
DDC144EU	47kΩ	47kΩ
DDC114YU	10kΩ	47kΩ
DDC123JU	2.2kΩ	47kΩ
DDC114EU	10kΩ	10kΩ
DDC143XU	4.7kΩ	10kΩ
DDC143ZU	4.7kΩ	47kΩ
DDC115EU	100kΩ	100kΩ

SOT363

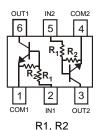


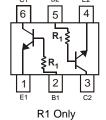
Top View

Mechanical Data

- Package: SOT363
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ³
- Weight: 0.006 grams (Approximate)

Part Number	R1 Only
DDC113TU	1kΩ
DDC143TU	4.7kΩ
DDC114TU	10kO





Device Schematic

Ordering Information (Notes 4, 5)

Part Number	Status	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DDC124EU-7-F	Active	N17	7	8	3,000
DDC124EUQ-7-F	NRND (Use ADC124EUQ)	N17	7	8	3,000
DDC144EU-7-F	Active	N20	7	8	3,000
DDC114YU-7-F	Active	N14	7	8	3,000
DDC114YUQ-7-F	NRND (Use ADC114YUQ)	N14	7	8	3,000
DDC114YUQ-13-F	NRND (Use ADC114YUQ)	N14	13	8	10,000
DDC123JU-7-F	Active	N06	7	8	3,000
DDC114EU-7-F	Active	N13	7	8	3,000
DDC114EUQ-7-F	NRND (Use ADC114EUQ)	N13	7	8	3,000
DDC114EUQ-13-F	NRND (Use ADC114EUQ)	N13	13	8	10,000
DDC113TU-7-F	Active	N01	7	8	3,000
DDC143TU-7-F	Active	N07	7	8	3,000
DDC114TU-7-F	Active	N12	7	8	3,000
DDC114TUQ-7-F	Active	N12	7	8	3,000
DDC143XU-7	Active	N04	7	8	3,000
DDC143XU-13	Active	N04	13	8	10,000
DDC143ZU-7-F	Active	N03	7	8	3,000
DDC115EU-7-F	Active	N02	7	8	3,000

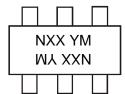
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
- 5. NRND = Not Recommended for New Design.



Marking Information

SOT363



NXX = Product Type Marking Code (See Ordering Information) YM = Date Code Marking

Y or \overline{Y} = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Kev

410 0040 110)												
Year	2002		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0		J	K	L	М	N	0	Р	R	S	Т
Month	la	Fals	Man	A	Mari	line	l. d	Aug	Con	Oot	Nov	Doo
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Cha	racteristic	Symbol	Value	Unit	
Supply Voltage		Vo	50	V	
Input Voltage	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC113TU DDC143TU DDC144TU DDC143XU DDC143XU DDC143XU DDC143ZU DDC143ZU DDC115EU	Vı	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5V max -5V max -5V max -7 to +20 -5 to +30 -10 to +40	V	
Output Current	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC113TU DDC143TU DDC144TU DDC143XU DDC143XU DDC143ZU DDC143ZU DDC143ZU DDC115EU	lo	30 30 70 100 50 100 100 100 100 100	mA	
Peak Output Current	•	Ісм	100	mA	

Thermal Characteristics (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6 & 7)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 6. Mounted on FR-4 PC Board with minimum recommended pad layout.

7. 150mW per element must not be exceeded.



Electrical Characteristics (@ $T_A = +25^{\circ}C$, unless otherwise specified.) For R1 Only Devices: DDC113TU & DDC143TU & DDC114TU

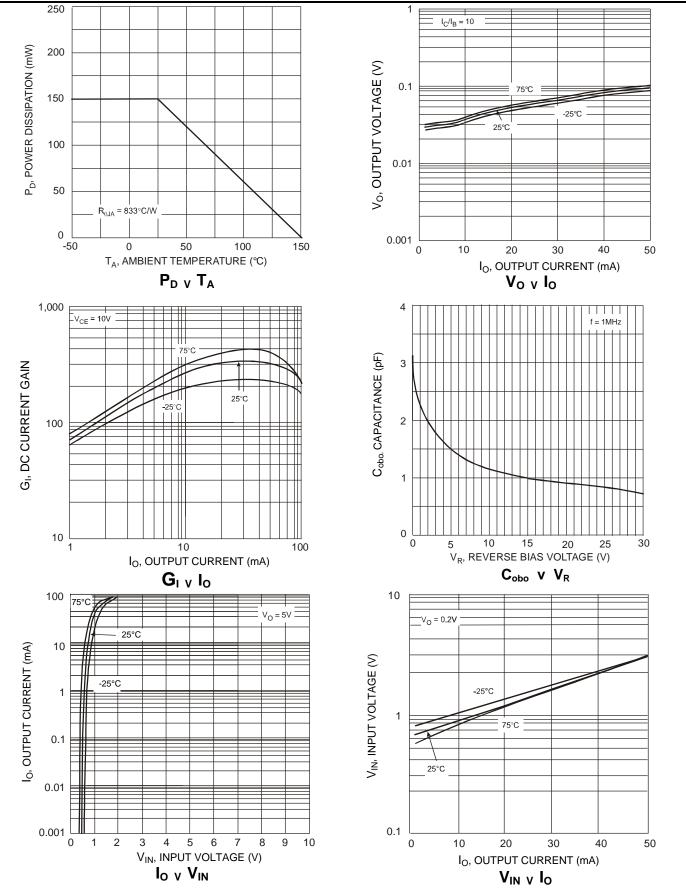
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50			V	$I_C = 50\mu A$
Collector-Emitter Breakdown Voltage	BV _{CEO}	50			V	$I_C = 1mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	5			V	I _E = 50μA
Collector Cutoff Current	I _{CBO}			0.5	μA	$V_{CB} = 50V$
Emitter Cutoff Current	I _{EBO}			0.5	μΑ	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage	V _{CE(sat)}			0.3	V	$I_C/I_B = 2.5 \text{mA} / 0.25 \text{mA}$ DDC143TU $I_C/I_B = 1 \text{mA} / 0.1 \text{mA}$ DDC114TU $I_C/I_B = 10 \text{mA} / 1 \text{mA}$ DDC113TU
DC Current Transfer Ratio	h _{FE}	100	250	600		$I_C = 1$ mA, $V_{CE} = 5$ V
Input Resistor (R ₁) Tolerance	ΔR_1	-30	_	+30	%	_
Transition frequency (Note 8)	f _T	_	250	_	MHz	$V_{CE} = 10V$, $I_{E} = -5mA$, $f = 100MHz$

Electrical Characteristics (@ $T_A = +25^{\circ}C$, unless otherwise specified.) For R1, R2 Devices: DDC124EU& DDC144EU& DDC114YU& DDC123JU& DDC114EU& DDC115EU

Characterist	ic	Symbol	Min	Тур	Max	Unit	Test Condition
	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143XU DDC143ZU DDC115EU	$V_{I(off)}$	0.5 0.5 0.5 0.5 0.5 0.5 0.5	1.1 1.1 — — 1.1 —	_		V _{CC} = 5V, I _O = 100μA
Input Voltage	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143XU DDC143ZU DDC115EU	V _{I(on)}	1	1.9 1.9 — — 1.9 — —	3.0 3.0 1.4 1.1 3.0 2.5 1.3 3	V	$\begin{split} &V_O = 0.3V, \ I_O = 5mA \\ &V_O = 0.3V, \ I_O = 2mA \\ &V_O = 0.3V, \ I_O = 1mA \\ &V_O = 0.3V, \ I_O = 5mA \\ &V_O = 0.3V, \ I_O = 10mA \\ &V_O = 0.3V, \ I_O = 20mA \\ &V_O = 0.3V, \ I_O = 5mA \\ &V_O = 0.3V, \ I_O = 1mA \end{split}$
Output Voltage	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143XU DDC143ZU DDC115EU	V _{O(on)}		0.1	0.3	٧	$I_O/I_1 = 10\text{mA} / 0.5\text{mA}$ $I_O/I_1 = 10\text{mA} / 0.5\text{mA}$ $I_O/I_1 = 5\text{mA} / 0.25\text{mA}$ $I_O/I_1 = 5\text{mA} / 0.25\text{mA}$ $I_O/I_1 = 10\text{mA} / 0.5\text{mA}$ $I_O/I_1 = 10\text{mA} / 0.5\text{mA}$ $I_O/I_1 = 5\text{mA} / 0.25\text{mA}$ $I_O/I_1 = 5\text{mA} / 0.25\text{mA}$ $I_O/I_1 = 10\text{mA} / 0.25\text{mA}$
Input Current	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU DDC143XU DDC143ZU DDC115EU	lı			0.36 0.18 0.88 3.6 0.88 1.8 1.8	mA	V ₁ = 5V
Output Current		I _{O(off)}	_	_	0.5	μΑ	$V_{CC} = 50V, V_{I} = 0V$
DC Current Gain	DDC124EU DDC144EU DDC114YU DDC114YUQ DDC123JU DDC114EU DDC143XU DDC143ZU DDC115EU	Gı	56 68 68 80 30 30 80 82	_	_	_	V _O = 5V, I _O = 5mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA
Input Resistor (R ₁) Tolerance		ΔR_1	-30		+30	%	
Resistance Ratio Tolerance		$\Delta(R_2/R_1)$	-20		+20	%	_
Transition frequency (Note 8)		f _T		250	_	MHz	$V_{CE} = 10V, I_E = 5mA, f = 100MHz$

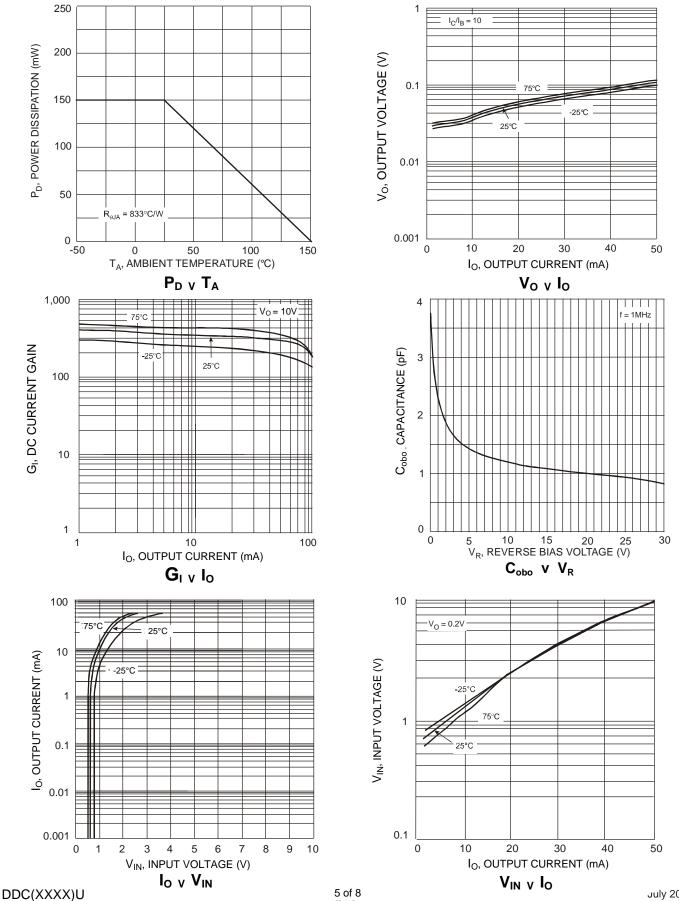


Typical Curves - DDC123JU (@ T_A = +25°C, unless otherwise specified.)



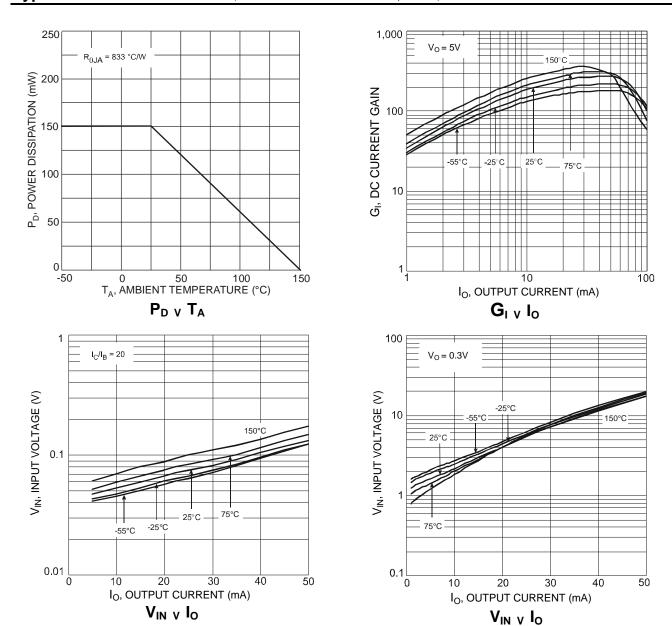


Typical Curves - DDC114YU (@ T_A = +25°C, unless otherwise specified.)





Typical Curves - DDC124EU (@ T_A = +25°C, unless otherwise specified.)

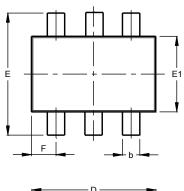


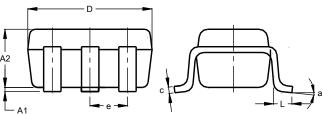


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



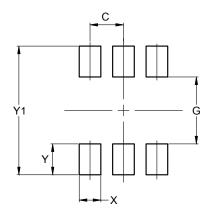


	SOT363							
Dim	Min	Тур						
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.10	0.30	0.25					
C	0.10	0.22	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	().650 E	SC					
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
ΔII	Dimen	sions	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)
C	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500



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DTC114EUA-TP SMUN5237DW1T1G SMUN5213DW1T1G SMUN5114DW1T1G DTC124ECA-TP DTA114ECA-TP DTC113EM3T5G

NSVMUN5135DW1T1G NSVMUN2237T1G NSVDTC143ZM3T5G SMUN5335DW1T2G SMUN5216DW1T1G NSVMUN5316DW1T1G

NSVMUN5215DW1T1G NSVMUN5213DW1T3G NSVIMD10AMT1G NSVEMC2DXV5T1G NSVDTC144WET1G NSVDTC123JET1G

NSVDTA143EM3T5G NSVB1706DMW5T1G NSBC143EDP6T5G NSBA144WDXV6T1G DTA115TET1G NSBC115TDP6T5G

NSBA113EF3T5G MUN2235T1G NSBC143ZDXV6T5G NSVDTA114EM3T5G MUN2138T1G DCX124EUQ-7-F MUN2141T1G

DTC144TET1G MUN2238T1G SMUN5112DW1T1G NSVMUN5131T1G